

DPG60IM300PC

HiPerFRED $V_{RRM} = 300 V_{RRM}$

 $I_{FAV} = 60 A$

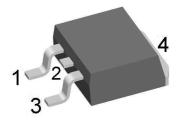
 $t_{rr} = 35 \, \text{ns}$

High Performance Fast Recovery Diode Low Loss and Soft Recovery Single Diode

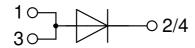
Part number

DPG60IM300PC

Marking on Product: DPG60IM300PC



Backside: cathode



Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low Irm-values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low Irm reduces:
 - Power dissipation within the diode
 - Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

Package: TO-263 (D2Pak)

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

Disclaimer Notice

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Fast Diode				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V _{RSM}	max. non-repetitive reverse blocki	ng voltage	$T_{VJ} = 25^{\circ}C$			300	V
V_{RRM}	max. repetitive reverse blocking ve	oltage	$T_{VJ} = 25^{\circ}C$			300	٧
I _R	reverse current, drain current	$V_R = 300 \text{ V}$	$T_{VJ} = 25^{\circ}C$			1	μΑ
		$V_R = 300 \text{ V}$	$T_{VJ} = 150$ °C			0.35	mΑ
V _F	forward voltage drop	I _F = 60 A	$T_{VJ} = 25^{\circ}C$			1.43	V
		$I_{F} = 120 \text{ A}$				1.78	٧
		I _F = 60 A	T _{vJ} = 150°C			1.14	V
		$I_F = 120 \text{ A}$				1.53	٧
I _{FAV}	average forward current	T _C = 135°C	$T_{VJ} = 175$ °C			60	Α
		rectangular d = 0.5					i
V _{F0}	threshold voltage		T _{vJ} = 175°C			0.69	٧
r _F	slope resistance	ss calculation only				6.4	mΩ
R _{thJC}	thermal resistance junction to case	9				0.45	K/W
R _{thCH}	thermal resistance case to heatsin	k			0.25		K/W
P _{tot}	total power dissipation		$T_{C} = 25^{\circ}C$			335	W
I _{FSM}	max. forward surge current	$t = 10 \text{ ms}$; (50 Hz), sine; $V_R = 0 \text{ V}$	$T_{VJ} = 45^{\circ}C$			550	Α
CJ	junction capacitance	$V_R = 150 \text{V}$ f = 1 MHz	$T_{VJ} = 25^{\circ}C$		80		pF
I _{RM}	max. reverse recovery current		$T_{VJ} = 25 ^{\circ}\text{C}$		3.5		Α
		$I_F = 60 \text{ A}; V_R = 200 \text{ V}$	$T_{VJ} = 125$ °C		9		Α
t _{rr}	reverse recovery time	$I_F = 60 \text{ A}; V_R = 200 \text{ V}$ - $di_F/dt = 200 \text{ A}/\mu\text{s}$	$T_{VJ} = 25 ^{\circ}C$		35		ns
	,	1	$T_{VJ} = 125^{\circ}C$		65		ns





Package TO-263 (D2Pak)			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I _{RMS}	RMS current	per terminal 1)			35	Α
T _{VJ}	virtual junction temperature		-55		175	°C
T _{op}	operation temperature		-55		150	°C
T _{stg}	storage temperature		-55		150	°C
Weight				1.5		g
F _c	mounting force with clip		20		60	N

¹⁾ I_{nust} is typically limited by the pin-to-chip resistance (1); or by the current capability of the chip (2). In case of (1) and a product with multiple pins for one chip-potential, the current capability can be increased by connecting the pins as one contact.

Part description

D = Diode

P = HiPerFRED

G = extreme fast

60 = Current Rating [A]

IM = Single Diode

300 = Reverse Voltage [V]

PC = TO-263AB (D2Pak) (2)

y Code No.	Quantity	Delivery Mode	Marking on Product	Ordering Number	Ordering
502404	800	Tape & Reel	DPG60IM300PC	DPG60IM300PC-TRL	Standard
523588	50	Tube	DPG60IM300PC	DPG60IM300PC-TUB	Alternative
_	50	Tube	DPG60IM300PC	DPG60IM300PC-TUB	Alternative

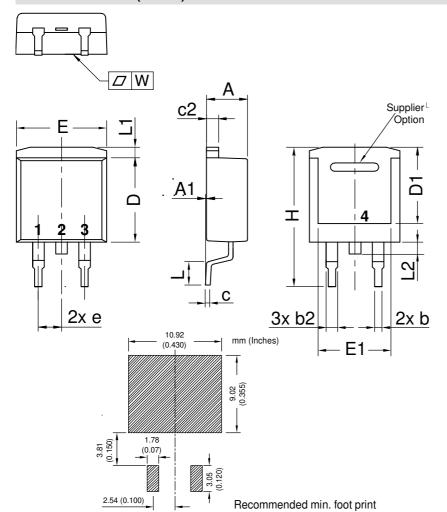
Similar Part	Package	Voltage class
DPG60l300HA	TO-247AD (2)	300

Equivalent Circuits for Simulation			* on die level	$T_{VJ} = 175^{\circ}C$
$I \rightarrow V_0$)— <u>R</u> o	Fast Diode		
V _{0 max}	threshold voltage	0.69		V
R _{0 max}	slope resistance *	3.2		mΩ





Outlines TO-263 (D2Pak)



	Millir	neter	Inc	hes	
Dim.	min	max	min	max	
Α	4.06	4.83	0.160	0.190	
A1	typ.	0.10	typ. 0	0.004	
A2	2.4		0.0	95	
b	0.51	0.99	0.020	0.039	
b2	1.14	1.40	0.045	0.055	
С	0.40	0.74	0.016	0.029	
c2	1.14	1.40	0.045	0.055	
D	8.38	9.40	0.330	0.370	
D1	8.00	8.89	0.315	0.350	
D2	2	.5	0.0	.098	
Е	9.65	10.41	0.380	0.410	
E1	6.22	8.50	0.245	0.335	
е	2,54 BSC		0,100 BSC		
e1	4.28		0.169		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	1.02	1.68	0.040	0.066	
W	typ. 0.02	0.040	typ. 0.0008	0.002	

All dimensions conform with and/or within JEDEC standard.

